

ATTENUATOR AND POWER PIN DIODES 2 - 30 MHz

RoHS Compliant Versions Available



DESCRIPTION

UM2100 Series PIN diodes are designed for transmit/receive switch and attenuator applications in HF band (2-30MHz) and below. As series configured switches, these long lifetime (25µs typical) diodes can control up to 2.5 kW, CW in a 50 ohm system. In HF band, insertion loss is less than 0.25dB and isolation is greater than 32dB (off-state).

The UM2100 series offers the lowest distortion performance in both the transmit and receive modes. Less than 50 mA forward bias is requires to obtain an IP3 of 60 dBm at 300 kHz with 1 watt per tone. The forward biased resistance/reactance vs. frequency characteristics are flat down to 10 kHz. The capacitance vs. reverse bias voltage characteristic is flat down to 2 MHz. In attenuator configuration, the UM2100 produces extremely low distortion at low values of attenuator control current, and very low insertion loss (0.2dB) in the "0dB" attenuator state.

IMPORTANT: For the most current data, consult MICROSEMIs website: www.MICROSEMI.com

These devices are ESD sensitive and must be handled use using ESD precautions.



KEY FEATURES

- HF band (2-30 MHz) PIN
- Long Lifetime (25µs typical)
- High Power (1kW, CW)
- High Isolation (32dB)
- Low Loss (0.25dB)
- Very Low Distortion (IP3=60dBm)
- Voltage ratings to 1000 V
- RoHS compliant packaging Available¹ (use UMX2101B, etc.)

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)						
Package	Conditions	(P _D) Power Dissapation (W)	(Θ)Thermal Resistance (°C/W)			
Α	25 ^O C Pin Temperature	25	50V			
В	½ in. total length to 25 ^O C	12	12.5			
E	Contact Free Air	2.5				
С	25 °C Stud Temperature	25	6			
D	25 °C Stud Temperature	18.75	8			
SM	25 °C End Cap Temperature	15	10			
ALL	1 us pulse (Single)	100KW	_			
ALL	Storage Temperature (T _{OP})	-65 ^O C	-65 °C to + 175 °C			
ALL	Operating Temperature (T _{OP})	-65 °C to + 175 °C				

¹ The UM2100 series of products can be supplied with a RoHS compliant finish (UMX2100) or with a 90/10 Sn/Pb finish. Consult factory for details.







APPLICATIONS/BENEFITS

- Isolated stud package available
- Surface mount package available
- Soldering temperature: 260 °C for 10 seconds maximum



ATTENUATOR AND POWER PIN DIODES 2 – 30 MHz

RoHS Compliant Versions Available

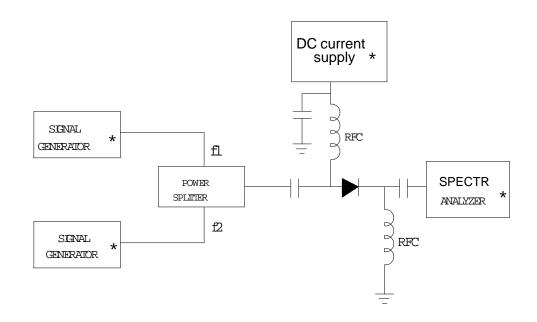


VOLTAGE RATINGS @ 25°C (unless otherwise specified) Reverse Voltage @ 10uA (V) **Part Number** UM2101 100 UM2102 200 UM2104 400 UM2106 600 800 UM2108 UM2110 1000



Parameter	Symbol	Conditions	MIN.	TYPICAL	MAX.	Units
Total Capacitance	C _T	V _R =100V, F= 1 MHz		1.9	2.5	pF
Series Resistance	Rs	If = 100 mA, F= 2 MHz		1.0	2.0	Ohms
Carrier Lifetime	TL	I _F = 10 mA/100 V	20	25		μs
Reverse Current	I _R	V _R = Voltage rating			10	μA
Intermodulation Distortion	IP3	P=2W total, I _F =25mA	50	60		dBm
		F1 = 1.999 MHz				
		F2 = 2.001 MHz				
		1.0 W/tone				

Intermodulation Distortion Test Circuit



* May be controlled with the IEEE-488 bus circuit.



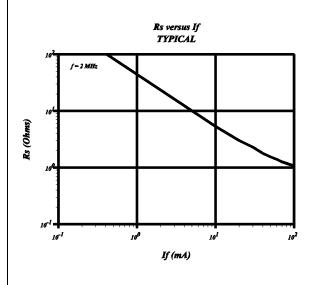
ATTENUATOR AND POWER PIN DIODES 2 - 30 MHz

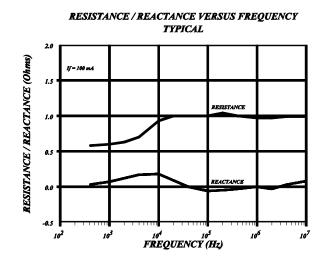
RoHS Compliant Versions Available



TYPICAL RS VS IF

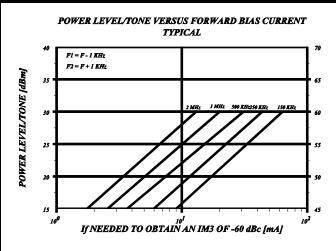
TYPICAL RS / REACTANCE VS FREQ

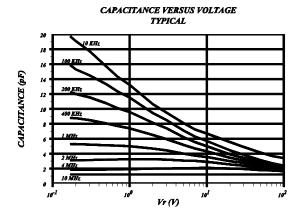




POWER/TONE VS

CAPACITANCE VS VOLTAGE





Copyright © 2006

Rev. A, 2007-02-26

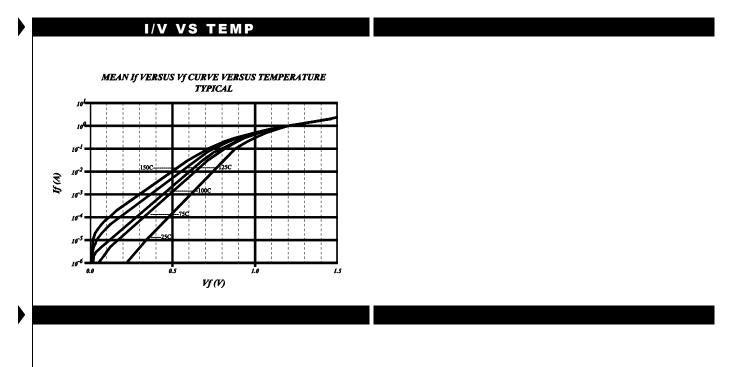
Microsemi



ATTENUATOR AND POWER PIN DIODES 2 – 30 MHz

RoHS Compliant Versions Available



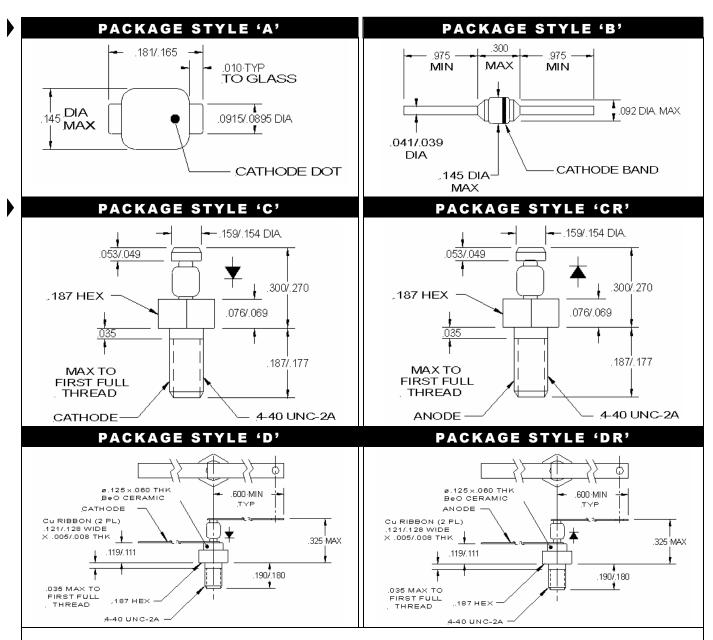




ATTENUATOR AND POWER PIN DIODES 2 – 30 MHz

RoHS Compliant Versions Available



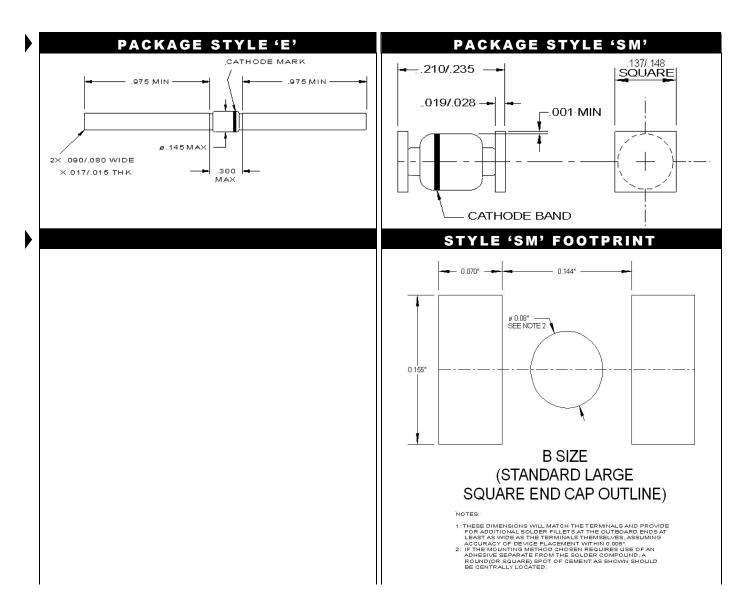




ATTENUATOR AND POWER PIN DIODES 2 - 30 MHz

RoHS Compliant Versions Available





NOTES:

- These dimensions will match the terminals and provide for additional solder fillets at the outboard ends at least as wide as the terminals themselves, assuming accuracy of placement within 0.005"
- If the mounting method chosen requires use of an adhesive separate from the solder compound, a round (or square) spot of cement as shown should be centrally located.



ATTENUATOR AND POWER PIN DIODES 2 – 30 MHz

RoHS Compliant Versions Available



NOTES